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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
09/765,044	01/19/2001	Chyi-Tsong Ni	TS00-355	6921	
28112 75	90 01/30/2004		EXAM	EXAMINER	
GEORGE O. SAILE & ASSOCIATES			BREWSTER,	BREWSTER, WILLIAM M	
28 DAVIS AVENUE POUGHKEEPSIE, NY 12603			ART UNIT	PAPER NUMBER	
	•		2823		

DATE MAILED: 01/30/2004

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)			
Advisory Action	09/765,044	NI ET AL.			
Advicery Action	Examiner	Art Unit			
	William M. Brewster	2823			
The MAILING DATE of this communication appears on the cover sheet with the correspondence address					
THE REPLY FILED 02 January 2004 FAILS TO PLACE Therefore, further action by the applicant is required to average final rejection under 37 CFR 1.113 may only be either: (1) condition for allowance; (2) a timely filed Notice of Appeal Examination (RCE) in compliance with 37 CFR 1.114.	oid abandonment of this applica) a timely filed amendment which	ation. A proper reply to a			
PERIOD FOR RE	PLY [check either a) or b)]				
a) The period for reply expires 3 months from the mailing date b) The period for reply expires on: (1) the mailing date of this A no event, however, will the statutory period for reply expire I ONLY CHECK THIS BOX WHEN THE FIRST REPLY WAS 706.07(f). Extensions of time may be obtained under 37 CFR 1.136(a). The fee have been filed is the date for purposes of determining the period of fee under 37 CFR 1.17(a) is calculated from: (1) the expiration date of (2) as set forth in (b) above, if checked. Any reply received by the Offic timely filed, may reduce any earned patent term adjustment. See 37 C	Advisory Action, or (2) the date set forth ater than SIX MONTHS from the mailing FILED WITHIN TWO MONTHS OF THE date on which the petition under 37 CFI of extension and the corresponding amounth that the shortened statutory period for reply the later than three months after the mail	g date of the final rejection. HE FINAL REJECTION. See MPEP R 1.136(a) and the appropriate extension unt of the fee. The appropriate extension originally set in the final Office action; or			
1. A Notice of Appeal was filed on Appellant's 37 CFR 1.192(a), or any extension thereof (37 CFF					
2. The proposed amendment(s) will not be entered be	ecause:				
(a) \(\square\) they raise new issues that would require further	er consideration and/or search (s	see NOTE below);			
(b) they raise the issue of new matter (see Note b	elow);				
 (c) they are not deemed to place the application in issues for appeal; and/or 	n better form for appeal by mate	rially reducing or simplifying the			
(d) they present additional claims without canceli	ng a corresponding number of fi	nally rejected claims.			
NOTE:					
3. Applicant's reply has overcome the following reject	ion(s):				
4. Newly proposed or amended claim(s) would canceling the non-allowable claim(s).	be allowable if submitted in a se	eparate, timely filed amendment			
5. ☐ The a) ☐ affidavit, b) ☐ exhibit, or c) ☐ request for application in condition for allowance because:	reconsideration has been consi	dered but does NOT place the			
6. The affidavit or exhibit will NOT be considered becaraised by the Examiner in the final rejection.	ause it is not directed SOLELY to	o issues which were newly			
7. For purposes of Appeal, the proposed amendment explanation of how the new or amended claims we					
The status of the claim(s) is (or will be) as follows:					
Claim(s) allowed:					
Claim(s) objected to:					
Claim(s) rejected:					
Claim(s) withdrawn from consideration:					
8. The drawing correction filed on is a) appr	oved or b) disapproved by the	ne Examiner.			
9. Note the attached Information Disclosure Statemer	nt(s)(PTO-1449) Paper N o(s)				
10.⊠ Other: <u>See Continuation Sheet</u>		~			
	W. Davi Primary	d Coleman Examiner			

Continuation of 10. Other: Paper received 2 January 2004, the applicant responds to the final rejection, sent 28 October 2003 2002. Applicant argues that the prior art of record Perng in view of Ngo does not teach the limitations of 1, 2, 8-11, 17-20, 26-31, and the prior art of record, Perng in view of Ngo, in further view of Tao does not teach the limitations of 3-7, 12-16, 21-25, 32-34.

As the examiner understands the claims as taught by the specification, applicant seeks to patent an invention which forms three oxide layers: 1) a pre-coat oxide of the CVD chamber walls with a PECVD oxide of a first deposition rate, displayed in fig. 1, layer 16, 2) placing a semiconductor wafer within the chamber, and depositing a second PECVD oxide with a thermal CVD rate, displayed in fig. 3, layer 22, and 3) depositing third oxide layer, consisting of a porous oxide different from the first PECVD oxide, displayed in fig. 3, layer 20. Perng teaches a method with step 2) placing a semiconductor wafer on the wafer chuck/heater within the CVD chamber, in fig. 3, the semiconductor wafer 306 including an upper second PECVD silicon oxide film 302, with TEOS, col. 10, line 50 - col. 11, line 8, preheating the chamber to about 400 C, col. 11, lines 9 - 37, having a second thermal CVD oxide deposition rate, and step 3) depositing a porous silicon oxide 5lm 312 upon the upper second PECVD silicon oxide film overlying the semiconductor wafer, thickness of less than about 10,000 A, col. 10, lines 26 - 39, with a lesser deposition rate, col. 11, lines 38 - 64, the porous silicon oxide film being different from the first PECVD silicon oxide film coating the CVD chamber inner walls.

Ngo teaches a method, with step 1) in fig. 3, of pre-coating 302 at least a podion of the CVD chamber inner walls with a layer of first PECVD silicon oxide film having a first thermal CVD oxide deposition rate thereupon, col. 2, lines 36 - 52, and step 2) then deposits a first layer of PECVD oxide, col. 3, lines 4 - 10. Ngo gives motivation in col. 1, lines 31-33, which facilitates producing a high quality, uniform and very thin PECVD oxide layer.

All of the previous cites were provided in Paper sent 28 October 2003.

As the pre-coat step may take place without the wafer inside it and as neither Perng nor Ngo restrict their use to just the steps stated, the inventions are combinable.

Tao teaches in fig. 2, forming a semiconductor substrate 30, and forming step 2) a second PECVD oxide 40 at a first rate, col. 7, lines 51-62., and step 3) depositing an oxide layer 42 with TEOS, col. 7, line 64 - col. 8, line 41. Tao gives motivation in col. 2, lines 13-56, aiding in forming vias though the oxide layers that have flat, instead of rounded bottoms.

Applicant argues that the combined references do not teach a difference in the deposition rates of the second and third oxide layers. Examiner disagrees. Perng in col. 10, lines 5-25 teaches an improved film quality and rate of deposition from the second oxide to the third qorous oxide. Tao teaches different flow rates from depositing the second oxide. col. 7, lines 51-64, and the third deposited oxide in col. 8, lines 26-41.

The end user may also optimize the temperature and flow rates to achieve the desired depositing rates.

As a rule, obviousness is based upon what the "references takes collectively would suggest to those of ordinary skill in the art." In re Rosselet, 146 USPQ 183, 186 (CCPA 1965). Furthermore, one cannot show non-obviousness by merely attacking references individually where the rejections are based on combinations of references. In re Keller, 208 USPQ 871 (CCPA 1981)., In re Merck & Co., Inc., 231 USPQ 375 (Fed. Cir. 1986). Instead, there must be an absence of "some teaching, suggestion or incentive supporting the prior art combination that produces the claimed invention." In re Bond, 15 USPQ2d 1566, 1568 (Fed. Cir. 1990). "Just as piecemeal reconstruction of the prior art by selecting teachings in light of (the) disclosure is contrary to the requirements of 35 USC â 103, so is the failure to consider as a whole the references collectively as well as individually." In re Passal. 165 USPQ 720, 723 (CCPA 1970). For the above reasons, the 103(a) rejections of Paper sent 28 October 2003 is proper.